

1 AMP ULTRAFAST RECOVERY DIODES

FEATURES

- PROPRIETARY **SOFT GLASS®** JUNCTION PASSIVATION FOR SUPERIOR RELIABILITY AND PERFORMANCE
- VOID FREE VACUUM DIE SOLDERING FOR MAXIMUM MECHANICAL STRENGTH AND HEAT DISSIPATION (Solder Voids: Typical $\leq 2\%$, Max. $\leq 10\%$ of Die Area)
- LOW SWITCHING NOISE
- LOW THERMAL RESISTANCE
- HIGH SWITCHING CAPABILITY
- LOW FORWARD VOLTAGE DROP

MECHANICAL DATA

- Case: JEDEC DO-41 molded epoxy (U/L Flammability Rating 94V-0)
- Terminals: Plated axial leads
- Solderability: Per MIL-STD 202 Method 208 guaranteed
- Polarity: Color band denotes cathode
- Mounting Position: Any
- Weight: 0.013 Ounces (0.35 Grams)

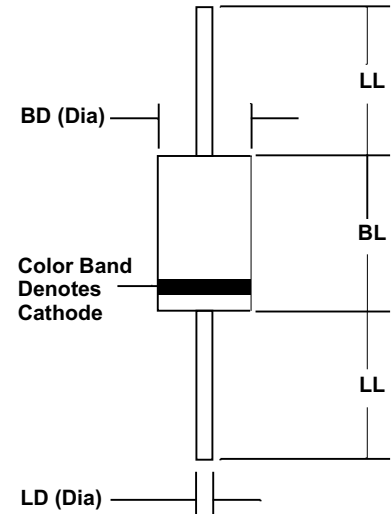
RoHS COMPLIANT

MECHANICAL SPECIFICATION

ACTUAL SIZE OF
DO-41 PACKAGE

SERIES UFR100 - UFR110

DO - 41



Sym	Minimum		Maximum	
	In	mm	In	mm
BL	0.160	4.1	0.205	5.2
BD	0.103	2.6	0.107	2.7
LL	1.00	25.4		
LD	0.028	0.71	0.034	0.86

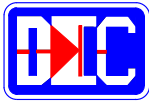
MAXIMUM RATINGS & ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive loads, derate current by 20%.

PARAMETER (TEST CONDITIONS)	SYMBOL	RATINGS										UNITS
Series Number		UFR 100	UFR 101	UFR 102	UFR 103	UFR 104	UFR 105	UFR 106	UFR 108	UFR 110		
Maximum DC Blocking Voltage	V _{RM}	50	100	200	300	400	500	600	800	1000	VOLTS	
Maximum RMS Voltage	V _{RMS}	35	70	140	210	280	350	420	560	700		
Maximum Peak Recurrent Reverse Voltage	V _{RRM}	50	100	200	300	400	500	600	800	1000		
Average Forward Rectified Current @ T _A = 55 °C	I _O	1										AMPS
Peak Forward Surge Current (8.3mS single half sine wave superimposed on rated load)	I _{FSM}	35										
Maximum Forward Voltage at 1 Amp DC	V _{FM}	1.25					1.7					VOLTS
Maximum Average DC Reverse Current @ T _C = 25°C	I _{RM}	2.0										μA
At Rated DC Blocking Voltage @ T _C = 125°C		50										
Typical Thermal Resistance, Junction to Ambient	R _{θJA}	50										°C/W
Typical Junction Capacitance (Note 1)	C _J	15										pF
Maximum Reverse Recovery Time (I _F =0.5A, I _R =1A, I _{RR} =0.25A)	T _{RR}	50					75					nSec
Junction Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150										°C

NOTES: (1) Measured at 1 MHz and an applied reverse voltage of 4 volts.

3.01 UFR100



1 AMP ULTRAFAST RECOVERY DIODES

RATING & CHARACTERISTIC CURVES FOR SERIES UFR100 - UFR110

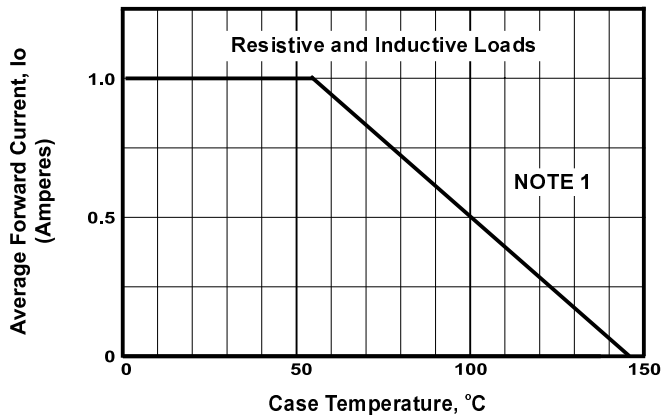


FIGURE 1. FORWARD CURRENT DERATING CURVE

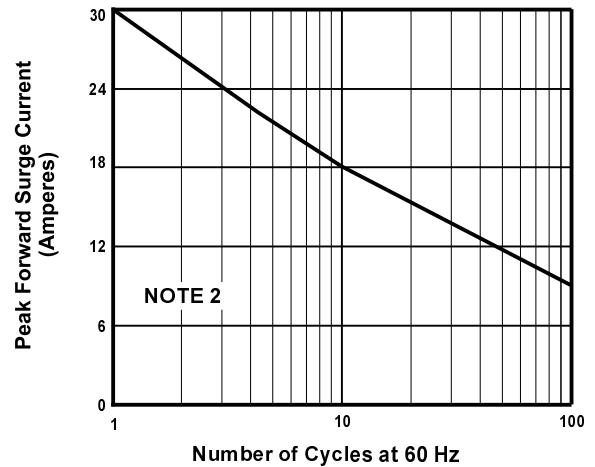


FIGURE 2. MAXIMUM NON-REPETITIVE SURGE CURRENT

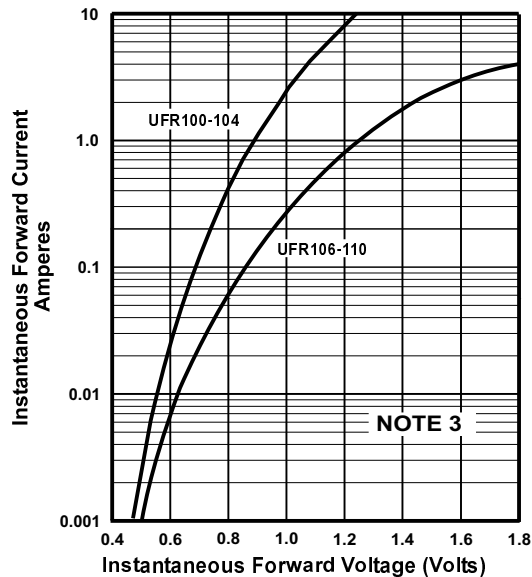


FIGURE 3. TYPICAL FORWARD CHARACTERISTICS

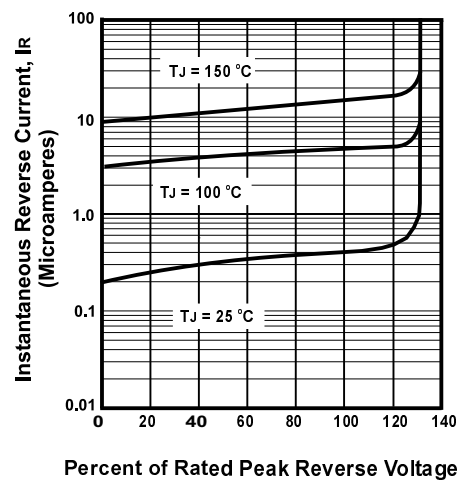


FIGURE 4. TYPICAL REVERSE CHARACTERISTICS

NOTES

- (1) Single Phase, Half Wave, 60 Hz; Lead Length = 0.375" (9.5mm)
- (2) JEDEC Method, 8.3 mSec. Single Half Sine Wave
- (3) $T_J = 25^\circ\text{C}$, Pulse Width = 300 μSec , 1.0% Duty Cycle
- (4) $T_J = 25^\circ\text{C}$, $f = 1.0\text{ MHz}$, 2% Duty Cycle.

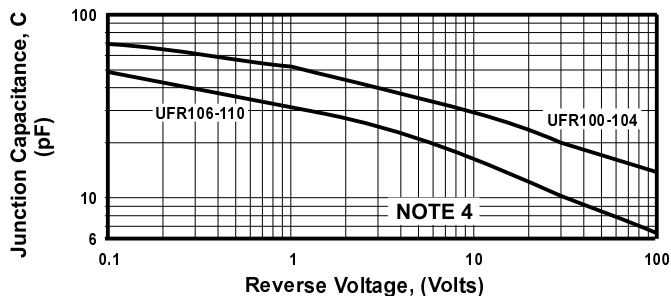


FIGURE 5. TYPICAL JUNCTION CAPACITANCE